NSN 5961-00-223-2230

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-223-2230 **Inclosure Material:** Metal **Overall Length:** 0.405 inches **Overall Diameter:** 0.437 inches **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 working peak reverse voltage **Current Rating Per Characteristic:** 12.00 amperes forward current, average absolute **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 190.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 tab, solder lug Shelf Life: N/a **Unit Of Measure:**

Demilitarization: No Fiig:

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